

## FEATURES

 High DC current gain : $hFE=200$ (Typ)  $VCE=6V$ ,  $IC=1mA$ 

 High voltage: $VCEO=50V$ 
**2SC1623(NPN)**

MAXIMUM RATINGS (TA=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	60	V
Collector-Emitter Voltage	$V_{CEO}$	50	V
Emitter-Base Voltage	$V_{EBO}$	5	V
Collector Current -Continuous	$I_C$	0.1	A
Collector Power Dissipation	$P_C$	0.2	W
Junction Temperature	$T_J$	150	°C
Storage Temperature	$T_{stg}$	-55 to +150	°C



ELECTRICAL CHARACTERISTICS (Tamb=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{CBO}$	$IC=100\mu A, IE=0$	60			V
Collector-emitter breakdown voltage	$V_{CEO}$	$IC=1mA, IB=0$	50			V
Emitter-base breakdown voltage	$V_{EBO}$	$IE=100\mu A, IC=0$	5			V
Collector cut-off current	$I_{CBO}$	$V_{CB}=60V, IE=0$			0.1	$\mu A$
Emitter cut-off current	$I_{EBO}$	$V_{EB}=5V, IC=0$			0.1	$\mu A$
DC current gain	$h_{FE}$	$V_{CE}=6V, IC=1mA$	90	200	600	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$IC=100mA, IB=10mA$			0.3	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$IC=100mA, IB=10mA$			1	V
Transition frequency	$f_T$	$V_{CE}=6V, IC=10mA$		250		MHz

 CLASSIFICATION OF  $h_{FE}$ 

Rank	L4	L5	L6	L7
Range	90-180	135-270	200-400	300-600

**2SC1623 Typical Characteristics**
